NSN 5961-01-357-1123

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-357-1123 **Inclosure Material:** Metal and ceramic **Overall Length:** 16.0 millimeters **Overall Width:** 14.0 millimeters **End Application:** B-2 bomber (atb) aircraft **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 12.0 collector to emitter voltage/static/base open and 20.0 collector to base voltage, dc and 2.5 emitter to base, rms **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Weapon system essential; junction pattern arrangement: npn **Terminal Type And Quantity:** 2 bonding pad and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No